MIC2183

Low Voltage Synchronous Buck PWM Control IC

Final Information

General Description

Micrel's MIC2183 is a high efficiency PWM synchronous buck control IC. With its wide input voltage range of 2.9V to 14V, the MIC2183 can be used to efficiently step voltages down in 1- or 2-cell Li Ion battery powered applications, as well as in fixed 3.3V, 5V, or 12V systems.

Efficiencies over 90% are achievable over a wide range of load conditions with the MIC2183's PWM control scheme. The operating frequency can be divided by two by raising the FREQ/2 pin to V_{DD}. This allows the user to optimize efficiency versus board space. It also allows the MIC2183 to be externally synchronized to frequencies below its nominal 400KHz.

The MIC2183 features an oscillator output, FreqOut, which can be used to implement a simple charge pump in low voltage applications. The output of the charge pump can be fed into the gate drive power circuitry via the V_{IN}P pin. This feature allows enhanced gate drive, hence higher efficiencies at low input voltages.

MIC2183 also features a 1µA shutdown mode, and a programmable undervoltage lockout, making it well-suited for portable applications.

The MIC2183 is available in 16-pin SOP and QSOP packaging options with a junction temperature range from -40°C to +125°C.

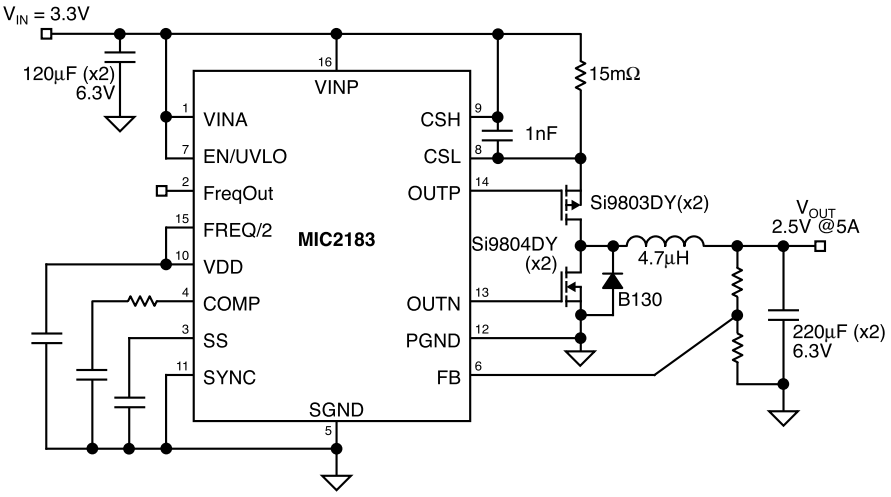
Features

- Input voltage range: 2.9V to 14V
- >90% efficiency
- Oscillator frequency of 400kHz
- Frequency divide-by-two pin
- Frequency sync to 600kHz
- FreqOut oscillator output allows simple charge pump implementation in low voltage systems
- Front edge blanking
- 5Ω output drivers (typical)
- Soft start
- PWM current mode control
- 1µA shutdown current
- Cycle-by-cycle current limiting
- Frequency foldback short circuit protection
- Adjustable under-voltage lockout
- 16-pin narrow-body SOP and QSOP package options

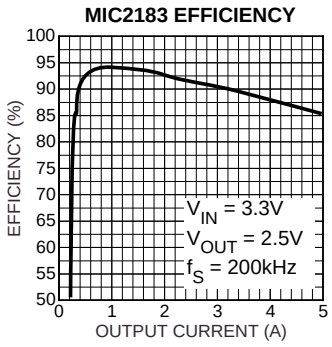
Applications

- 3.3V to 2.5V/1.8V/1.5V conversion
- DC power distribution systems
- Wireless modems
- ADSL line cards
- 1-and 2-cell Li Ion battery operated equipment
- Satellite Phones

Typical Application



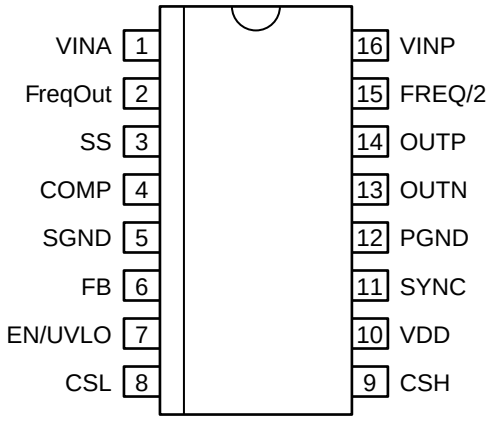
Adjustable Output Synchronous Buck Converter



Ordering Information

Part Number	Output Voltage	Frequency	Junction Temp. Range	Package
MIC2183BM	Adjustable	200/400KHz	–40°C to +125°C	16-lead SOP
MIC2183BQS	Adjustable	200/400KHz	–40°C to +125°C	16-lead QSOP

Pin Configuration



16 Lead SOIC (M)
16 Lead QSOP (QS)

Pin Description

Pin Number	Pin Name	Pin Function
1	VINA	Analog voltage input voltage to the circuit. This powers up the analog sections of the die and does not need to be the same voltage as Pin 16 ($V_{IN}P$).
2	FreqOut	This provides a digital signal output signal at half the switching frequency. This signal swings from 0 to 3V, and can be used to drive an external capacitive doubler to provide a higher voltage to the $V_{IN}P$ input.
3	SS	Soft start reduces the inrush current and delays and slows the output voltage rise time. A 5µA current source will charge the capacitor up to V_{DD}. A 1µF capacitor will soft start the switching regulator in 1.5ms.
4	COMP	Compensation (Output): Internal error amplifier output. Connect to a capacitor or series RC network to compensate the regulator's control loop.
5	SGND	Small signal ground: must be routed separately from other grounds to the (-) terminal of C_{OUT}.
6	FB	Feedback Input - the circuit regulates this pin to 1.245V.
7	EN/UVLO	Enable/UnderVoltage Lockout (input): A low level on this pin will power down the device, reducing the quiescent current to under 5uA. This pin has two separate thresholds, below 1.5V the output switching is disabled, and below 0.9V the part is forced into a complete micropower shutdown. The 1.5V threshold functions as an accurate undervoltage lockout (UVLO) with 140mV hysteresis.
8	CSL	The (-) input to the current limit comparator. A built in offset of 100mV between CSH and CSL in conjunction with the current sense resistor sets the current limit threshold level. This is also the (-) input to the current amplifier.
9	CSH	The (+) input to the current limit comparator. A built in offset of 100mV between CSH and CSL in conjunction with the current sense resistor sets the current limit threshold level. This is also the (+) input to the current amplifier.
10	VDD	3V internal linear-regulator output. V_{DD} is also the supply voltage bus for the chip. Bypass to SGND with 1µF.
11	SYNC	Frequency Synchronization (Input): Connect an external clock signal to synchronize the oscillator. Leading edge of signal above 1.5V starts the switching cycle. Connect to SGND if not used.
12	PGND	MOSFET driver power ground, connects to source of synchronous MOSFET and the (-) terminal of CIN.
13	OUTN	High current drive for synchronous N channel MOSFET. Voltage swing is from ground to V_{INP}. On-resistance is typically 5Ω.
14	OUTP	High current drive for high side P channel MOSFET. Voltage swing is from ground to $V_{IN}P$. On-resistance is typically 5Ω.
15	FREQ/2	When this is low, the oscillator frequency is 400KHz. When this pin is raised to V_{DD}, the oscillator frequency is 200KHz.
16	VINP	Power Input voltage to the circuit. The output gate drivers are powered from this supply. The current sense resistor R_{CS} should be connected as close as possible to this pin.

Absolute Maximum Ratings (Note 1)

Supply Voltage ($V_{IN}A$, $V_{IN}P$) 15V
Digital Supply Voltage (V_{DD}) 7V
Comp Pin Voltage (V_{COMP}) ..... –0.3V to +3V
Feedback Pin Voltage (V_{FB}) ..... –0.3V to +3V
Enable Pin Voltage ($V_{EN/UVLO}$) ..... –0.3V to 15V
Current Sense Voltage (V_{CSH}–V_{CSL}) ..... –0.3V to 1V
Sync Pin Voltage (V_{SYNC}) ..... –0.3V to 7V
Freq/2 Pin Voltage ($V_{FREQ/2}$) ..... -0.3V to 7V
Power Dissipation (P_D)
16 lead SOIC ..... 400mW @ T_A = 85°C
16 lead QSOP ..... 245mW @ 85°C
Ambient Storage Temp ..... –65°C to +150°C
ESD Rating, **Note 3**

Operating Ratings (Note 2)

Supply Voltage ($V_{IN}A$, $V_{IN}P$) ..... +2.9V to +14V
Ambient Operating Temperature ..... $–40°C \le T_A \le +85°C$
Junction Temperature ..... $–40°C \le T_J \le +125°C$
Output Voltage Range ..... 1.3V to 12V
PackageThermal Resistance
θ_{JA} 16-lead SOP ..... 100°C/W
θ_{JA} 16-lead QSOP ..... 163°C/W

Electrical Characteristics

$V_{IN}A = V_{IN}P = V_{CSH}$ = 5V, V_{OUT} = 3.3V, $V_{EN/UVLO}$ = 5V, $V_{FREQ/2}$ = 0V, T_J = 25ºC, unless otherwise specified. **Bold** values indicate $–40ºC < T_J < +125ºC$.

Parameter	Condition	Min	Typ	Max	Units
Regulation					
Feedback Voltage Reference	(±1%)	1.233	1.245	1.257	V
	(±2%)	**1.22**		**1.27**	V
Feedback Bias Current			50		nA
Output Voltage Line Regulation	$5V \le V_{IN} \le 12V$		0.04		% / V
Output Voltage Load Regulation	$0mV < (V_{CSH} – V_{CSL}) < 75mV$		0.9		%
Output Voltage Total Regulation	$5V \le V_{IN}A \le 12V$, $0mV < (V_{CSH} – V_{CSL}) < 75mV$ (±3%)	1.208		1.282	V
Input & V_{DD} Supply					
$V_{IN}A$ Input Current			0.7		mA
$V_{IN}P$ Input Current, **Note 4**	(Excluding external MOSFET gate current)		1.0		mA
Shutdown Quiescent Current	$V_{EN/UVLO}$ = 0V; ($I_{VINA} + I_{VINP}$)		0.5	5	µA
Digital Supply Voltage (V_{DD})	I_L = 0	2.82	3.0	3.18	V
Digital Supply load regulation	I_L = 0 to 1mA		0.03		V
Undervoltage Lockout	V_{DD} upper threshold (turn on threshold)		2.75		V
UVLO Hysteresis			100		mV
Enable/UVLO					
Enable Input Threshold		0.6	0.9	1.2	V
UVLO Threshold	(turn-on threshold)	1.4	1.5	1.6	V
UVLO Hysteresis			140		mV
Enable Input Current	$V_{EN/UVLO}$ = 5V		0.2	5	µA
Soft Start					
Soft Start Current			5		µA
Current Limit					
Current Limit Threshold Voltage	Voltage on CSH-CSL to trip current limit		100		mV
Error Amplifier					
Error Amplifier Gain			20		V/V
Current Amplifier					
Current Amplifier Gain			3.0		V/V

Parameter	Condiion	Min	Typ	Max	Units
Oscillator Section					
Oscillator Frequency (f_O)		360	400	440	kHz
Maximum Duty Cycle	V_{FB} = 1.0V	100			%
Minimum On Time	V_{FB} = 1.5V		165		ns
Freq/2 Frequency (f_O)	$V_{Freq/2}$ = 5V	170	200	230	kHz
Frequency Foldback Threshold	Measured on FB		0.3		V
Frequency Foldback Frequency			90		kHz
SYNC Threshold Level		0.6	1.4	2.2	V
SYNC Input Current			0.1	5	µA
SYNC Minimum Pulse Width		200			ns
SYNC Capture Range	**Note 5**	f_0 +15 %		600	kHz
FreqOut Output					
FreqOut Frequency	**Note 6**		f_O / 2		kHz
FreqOut Current Drive	Sink		8		mA
	Source		–6		mA
Gate Drivers					
Rise/Fall Time	C_L = 3300pF		50		ns
Output Driver Impedance	Source; $V_{IN}P$ = 12V		4	**8**	Ω
	Sink; $V_{IN}P$ = 12V		3	**7**	Ω
	Source; $V_{IN}P$ = 5V		5	**11**	Ω
	Sink; $V_{IN}P$ = 5V		5	**11**	Ω
Driver Non-Overlap Time	$V_{IN}P$ = 12V		50		ns
	$V_{IN}P$ = 5V		80		ns

Note 1: Absolute maximum ratings indicate limits beyond which damage to the component may occur. Electrical specifications do not apply when operating the device outside of its operating ratings. The maximum allowable power dissipation is a function of the maximum junction temperature, T_J(Max), the junction-to-ambient thermal resistance, θ_{JA}, and the ambient temperature, T_A.

Note 2. The device is not guaranteed to function outside its operating rating.

Note 3. Devices are ESD sensitive. Handling precautions recommended.

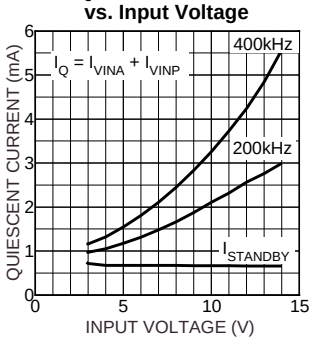
Note 4: See application information for I($V_{IN}P$) vs. $V_{IN}P$.

Note 5: See application information for limitations on maximum operating frequency.

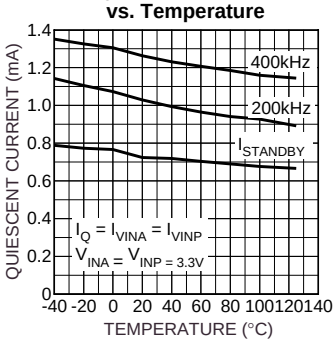
Note 6: The frequency on FreqOut is half the frequency of the oscillator, or half the frequency of the external Sync signal.

Typical Characteristics

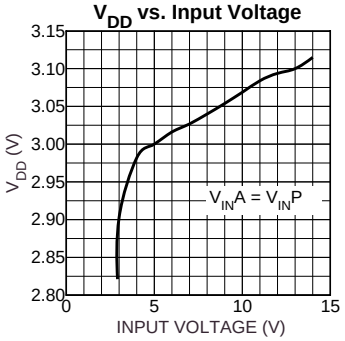
Quiescent Current vs. Input Voltage



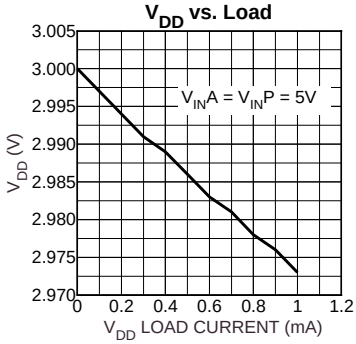
Quiescent Current vs. Temperature



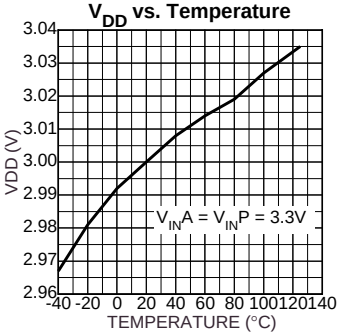
V_{DD} vs. Input Voltage



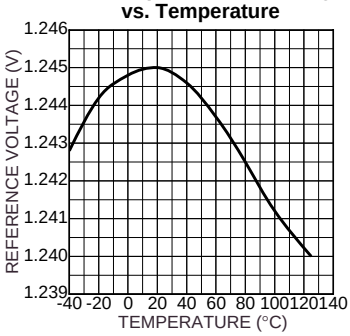
V_{DD} vs. Load



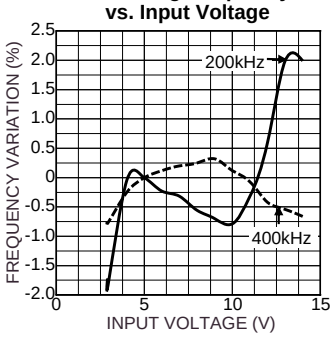
V_{DD} vs. Temperature



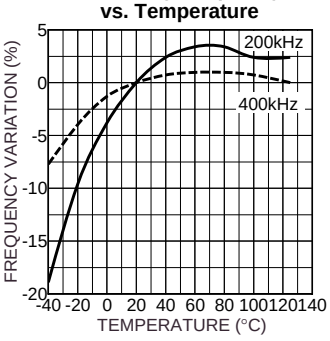
Error Amp Reference Voltage vs. Temperature



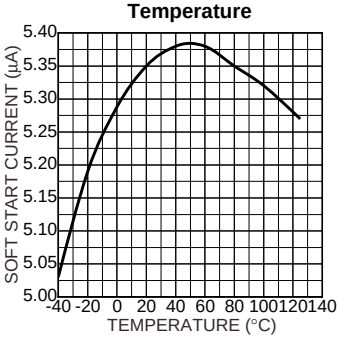
Switching Frequency vs. Input Voltage



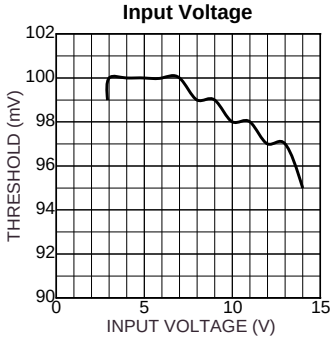
Switching Frequency vs. Temperature



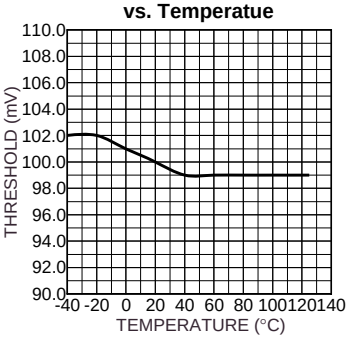
Soft Start Current vs. Temperature



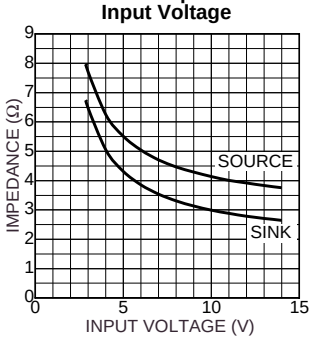
Overcurrent Threshold vs. Input Voltage



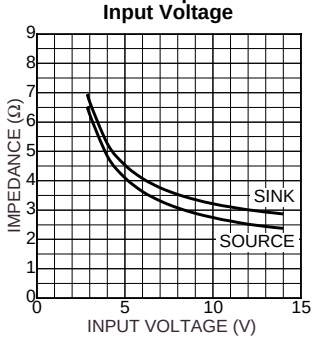
Overcurrent Threshold vs. Temperatue



OUTN Drive Impedance vs. Input Voltage



OUTP Drive Impedance vs. Input Voltage



Functional Diagram

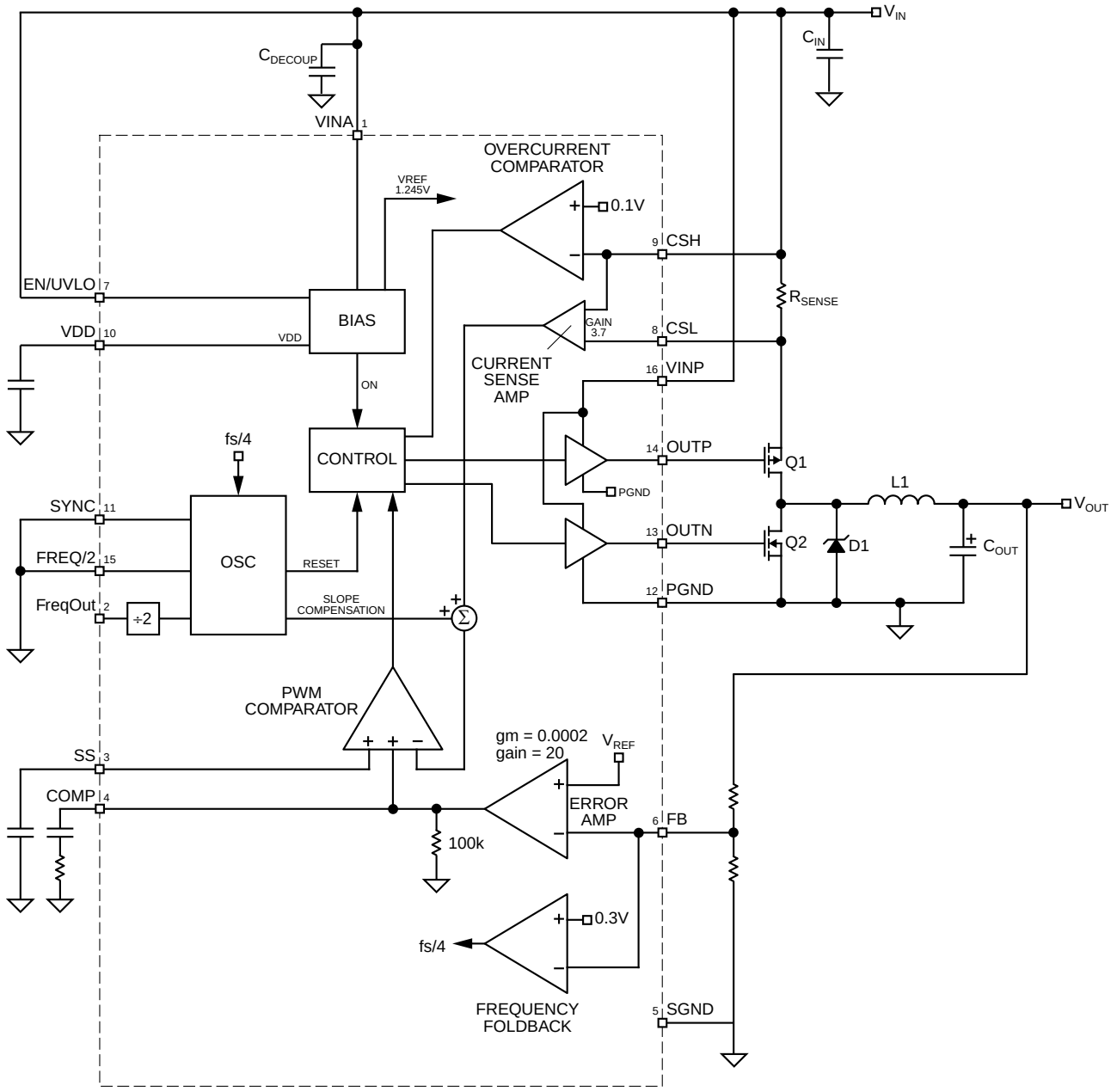


Figure 1. MIC2183 Block Diagram

Functional Characteristics

Controller Overview and Functional Description

The MIC2183 is a BiCMOS, switched mode, synchronous, step down (buck) converter controller. It uses both N and P-Channel MOSFETs, which allows the controller to operate at 100% duty cycle and eliminates the need for a high side drive bootstrap circuit. Current mode control is used to achieve superior transient line and load regulation. An internal corrective ramp provides slope compensation for stable operation above a 50% duty cycle. The controller is optimized for high efficiency, high performance DC-DC converter applications.

Figure 1 is a block diagram of the MIC2183 configured as a synchronous buck converter. At the beginning of the switching cycle, the OUTP pin pulls low and turns on the high-side P-Channel MOSFET, Q1. Current flows from the input to the output through the current sense resistor, MOSFET and inductor. The current amplitude increases, controlled by the inductor. The voltage developed across the current sense resistor, R_{SENSE}, is amplified inside the MIC2183 and combined with an internal ramp for stability. This signal is compared to the output of the error amplifier. When the current signal equals the error voltage signal, the P-channel MOSFET is turned off. The inductor current flows through the diode, D1, until the synchronous, N-Channel MOSFET turns on. The voltage drop across the MOSFET is less than the forward voltage drop of the diode, which improves the converter efficiency. At the end of the switching period, the synchronous MOSFET is turned off and the switching cycle repeats.

The MIC2183 controller is broken down into 7 functions.

- Control loop
  - PWM operation
  - Current mode control
- Current limit
- Reference, enable and UVLO
- FreqOut
- MOSFET gate drive
- Oscillator and Sync
- Soft-start

Control Loop

PWM Control Loop

The MIC2183 uses current mode control to regulate the output voltage. This dual control loop method (illustrated in Figure 2) senses the output voltage (outer loop) and the inductor current (inner loop). It uses inductor current and output voltage to determine the duty cycle of the buck converter. Sampling the inductor current effectively removes the inductor from the control loop, which simplifies compensation.

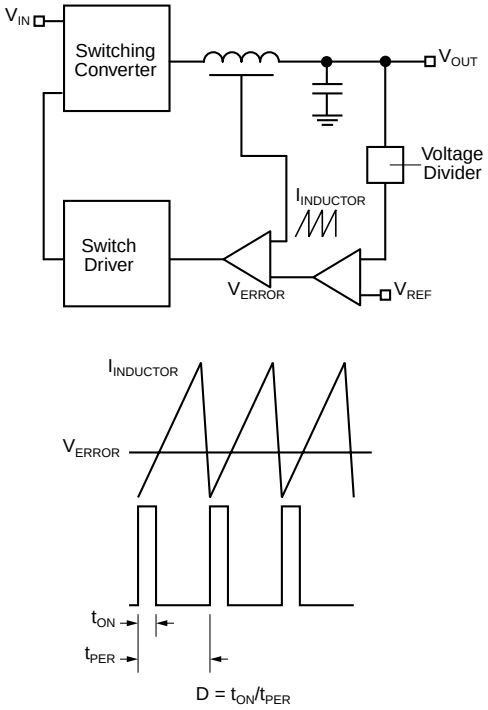


Figure 2. Current Mode Control Example

As shown in Figure 1, the inductor current is sensed by measuring the voltage across the resistor, R_{SENSE}. A ramp is added to the amplified current sense signal to provide slope compensation, which is required to prevent unstable operation at duty cycles greater than 50%.

A transconductance amplifier is used for the error amplifier, which compares an attenuated sample of the output voltage with a reference voltage. The output of the error amplifier is the compensation pin (Comp), which is compared to the current sense waveform in the PWM block. When the current signal becomes greater than the error signal, the comparator turns off the high side drive. The COMP pin provides access to the output of the error amplifier and allows the use of external components to stabilize the voltage loop.

Current Limit

The output current is detected by the voltage drop across the external current sense resistor (R_{SENSE} in Figure 1.). The current sense resistor must be sized using the minimum current limit threshold. The external components must be designed to withstand the maximum current limit. The current sense resistor value is calculated by the equation below:

$$R_{SENSE} = \frac{MIN_CURRENT_SENSE_THRESHOLD}{I_{OUT_MAX}}$$

The maximum output current is:

$$I_{OUT_MAX} = \frac{MAX_CURRENT_SENSE_THRESHOLD}{R_{SENSE}}$$

The current sense pins CSH (pin 9) and CSL (pin 8) are noise sensitive due to the low signal level and high input impedance. The PCB traces should be short and routed close to each other. A small (1nF) capacitor across the pins will attenuate high frequency switching noise.

When the peak inductor current exceeds the current limit threshold, the overcurrent comparator turns off the high side MOSFET for the remainder of the switching cycle, effectively decreasing the duty cycle. The output voltage drops as additional load current is pulled from the converter. When the voltage at the feedback pin (FB) reaches approximately 0.3V, the circuit enters frequency foldback mode and the oscillator frequency will drop to 1/4 of the switching frequency. This limits the maximum output power delivered to the load under a short circuit condition.

Reference, Enable and UVLO Circuits

The output drivers are enabled when the following conditions are satisfied:

- The V_{DD} voltage (pin 10) is greater than its undervoltage threshold.
- The voltage on the enable pin (pin 7) is greater than the enable UVLO threshold.

The enable pin (pin 7) has two threshold levels, allowing the MIC2183 to shut down in a low current mode, or turn off output switching in standby mode. An enable pin voltage lower than the shutdown threshold turns off all the internal circuitry and places the MIC2183 in a micropower shutdown mode.

If the enable pin voltage is between the shutdown and standby thresholds, the internal bias, V_{DD} and reference voltages are turned on. The soft start pin is forced low by an internal discharge MOSFET. The output drivers are inhibited from switching. The OUTP pin is in a high state and the OUTN pin remains in a low state. Raising the enable voltage above the standby threshold allows the soft start capacitor to charge and enables the output drivers. The standby threshold is specified in the electrical characteristics. A resistor divider can be used with the enable pin to prevent the power supply from turning on until a specified input voltage is reached. The circuit in Figure 3 shows how to connect the resistors.

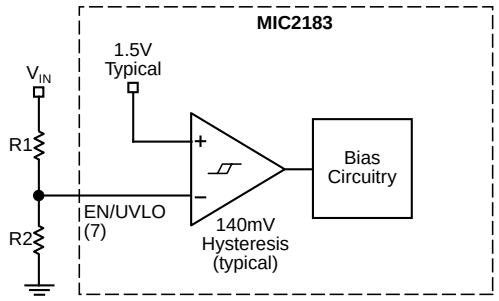


Figure 3. UVLO Circuitry

The line voltage turn on trip point is:

$$V_{INPUT_ENABLE} = V_{THRESHOLD} \times \frac{R2}{R1+R2}$$

where:

$V_{THRESHOLD}$ is the voltage level of the internal comparator reference, typically 1.5V

The input voltage hysteresis is equal to:

$$V_{INPUT_HYST} = V_{HYST} \times \frac{R1+R2}{R2}$$

where:

V_{HYST} is the internal comparator hysteresis level, typically 140mV.

V_{INPUT_HYST} is the hysteresis at the input voltage

The MIC2183 will be disabled when the input voltage drops back down to:

$$V_{INPUT_OFF} = V_{INPUT_ENABLE} - V_{INPUT_HYST} = (V_{THRESHOLD} - V_{HYST}) \times \frac{R2}{R1+R2}$$

Either of 2 UVLO conditions will pull the soft start capacitor low.

- When the V_{DD} voltage drops below its undervoltage lockout level.
- When the enable pin drops below the its enable threshold

The internal bias circuit generates an internal 1.245V bandgap reference voltage for the voltage error amplifier and a 3V V_{DD} voltage for the internal control circuitry. The V_{DD} pin must be decoupled with a 1µF ceramic capacitor. The capacitor must be placed close to the V_{DD} pin. The other end of the capacitor must be connected directly to the ground plane.

MOSFET Gate Drive

The MIC2183 is designed to drive a high side P-channel MOSFET and a low side N-channel MOSFET. The source pin of the P-channel MOSFET is connected to the input of the power supply. It is turned on when OUTP pulls the gate of the MOSFET low. The advantage of using a P-channel MOSFET is that it does not required a bootstrap circuit to boost the gate voltage higher than the input, as would be required for an N-channel MOSFET.

The $V_{IN}P$ pin (pin 16) supplies the drive voltage to both gate drive pins, OUTN and OUTP. $V_{IN}P$ pin is usually connected to the input supply. The $V_{IN}P$ pin and CSH pin must be connected to the same potential.

A non-overlap time is built into the MOSFET driver circuitry. This dead-time prevents the high-side and low-side MOSFET drivers from being on at the same time. Either an external diode or the low-side MOSFET internal parasitic diode conducts the inductor current during the dead-time.

MOSFET Selection

The P-channel MOSFET must have a V_{GS} threshold voltage equal to or lower than the input voltage when used in a buck converter topology. There is a limit to the maximum gate charge the MIC2183 will drive. Higher gate charge MOSFETs will slow down the turn-on and turn-off times of the MOSFETs. Slower transition times will cause higher power dissipation in the MOSFETs due to higher switching transition losses. The MOSFETs must be able to completely turn on and off within the driver non-overlap time If both MOSFETs are conducting at the same time, shoot-through will occur, which greatly increases power dissipation in the MOSFETs and reduces converter efficiency.

The MOSFET gate charge is also limited by power dissipation in the MIC2183. The power dissipated by the gate drive circuitry is calculated below:

$$P_{GATE_DRIVE} = Q_{GATE} \times V_{IN}P \times f_S$$

where: Qgate is the total gate charge of both the N and P-channel MOSFETs.

f_S is the switching frequency

$V_{IN}P$ is the gate drive voltage at the $V_{IN}P$ pin

The graph in Figure 4 shows the total gate charge that can be driven by the MIC2183 over the input voltage range, for different values of switching frequency.

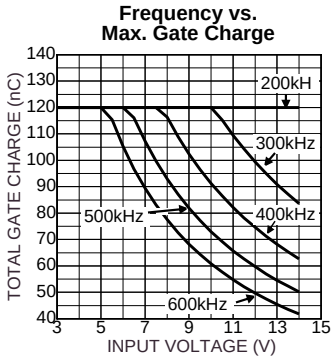


Figure 4. MIC2183 Frequency vs Max. Gate Charge

Oscillator & Sync

The internal oscillator is free running and requires no external components. The f/2 pin allows the user to select from two switching frequencies. A low level set the oscillator frequency to 400kHz and a high level set the oscillator frequency to 200kHz. The maximum duty cycle for both frequencies is 100%. This is another advantage of using a P-channel MOSFET for the high-side drive; it can continuously turned on.

A frequency foldback mode is enabled if the voltage on the feedback pin (pin 6) is less than 0.3V. In frequency foldback,

the oscillator frequency is reduced by approximately a factor of 4. Frequency foldback is used to limit the energy delivered to the output during a short circuit fault condition.

The SYNC input (pin 11) lets the MIC2183 synchronize with an external clock signal. The rising edge of the sync signal generates a reset signal in the oscillator, which turns off the low side gate drive output. The high side drive then turns on, restarting the switching cycle. The sync signal is inhibited when the controller operates in frequency foldback. The sync signal frequency must be greater than the maximum specified free running frequency of the MIC2183. If the synchronizing frequency is lower, double pulsing of the gate drive outputs will occur. When not used, the sync pin must be connected to ground.

The maximum recommended output switching frequency is 600kHz. Synchronizing to higher frequencies may be possible, however, higher power dissipation in the internal gate drive circuits will occur. The MOSFET gates require charge to turn on the device. The average current required by the MOSFET gate increases with switching frequency.

Soft Start

Soft start reduces the power supply input surge current at start up by controlling the output voltage risetime. The input surge appears while the output capacitance is charged up. A slower output risetime will draw a lower input surge current. Soft start may also be used for power supply sequencing.

The soft start voltage is applied directly to the PWM comparator. A 5µA internal current source is used to charge up the soft start capacitor. The capacitor is discharged when either the enable pin voltage drops below the standby threshold or the V_{DD} voltage drops below its UVLO level.

The part switches at a low duty cycle when the soft start pin voltage is zero. As the soft start voltage rises from 0V to 0.7V, the duty cycle increases from the minimum duty cycle to the operating duty cycle. The oscillator runs at the foldback frequency (1/4 of the switching frequency) until the feedback voltage rises above 0.3V. The risetime of the output is dependent of the soft start capacitor output capacitance, input and output voltage and load current.

Voltage Setting Components

The MIC2183 requires two resistors to set the output voltage as shown in Figure 5.

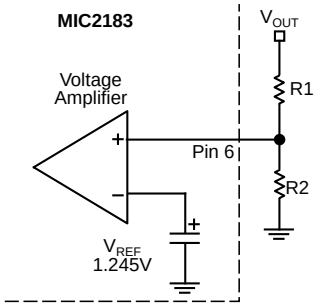


Figure 5

The output voltage is determined by the equation below.

$$V_{OUT} = V_{REF} \times 1 + \frac{R1}{R2}$$

Where: V_{REF} for the MIC2183 is typically 1.245V.

Lower values of R1 are preferred to prevent noise from appearing on the FB pin. A typically recommended value is 10kΩ. If R1 is too small in value it will decrease the efficiency of the power supply, especially at low output loads.

Once R1 is selected, R2 can be calculated with the following formula.

$$R2 = \frac{V_{REF} \times R1}{V_{OUT} - V_{REF}}$$

Efficiency Considerations

Efficiency is the ratio of output power to input power. The difference is dissipated as heat in the buck converter. Under light output load, the significant contributors are:

- The V_{IN}A supply current
- The V_{IN}P supply current, which includes the current required to switch the external MOSFETs
- Core losses in the output inductor

To maximize efficiency at light loads:

- Use a low gate charge MOSFET or use the smallest MOSFET, which is still adequate for maximum output current.
- Use a ferrite material for the inductor core, which has less core loss than an MPP or iron power core.

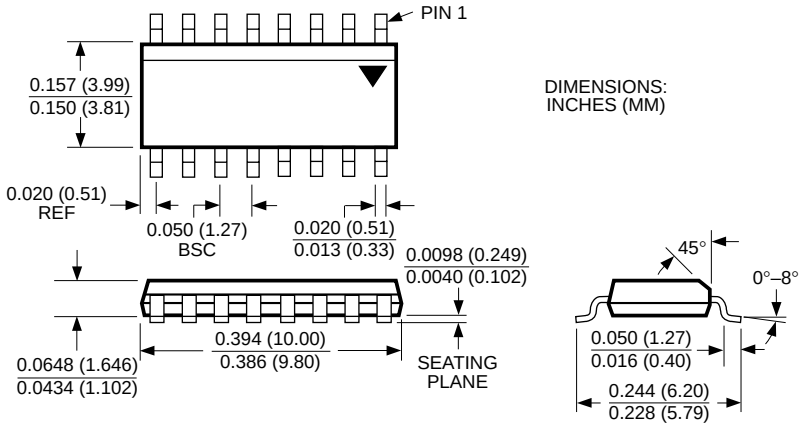
Under heavy output loads the significant contributors to power loss are (in approximate order of magnitude):

- Resistive on time losses in the MOSFETs
- Switching transition losses in the high side MOSFET
- Inductor resistive losses
- Current sense resistor losses
- Input capacitor resistive losses (due to the capacitors ESR)

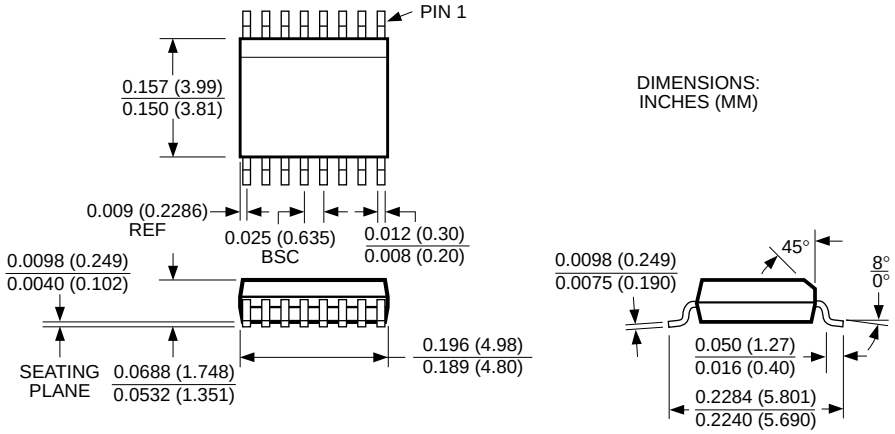
To minimize power loss under heavy loads:

- Use low on resistance MOSFETs. Use low threshold logic level MOSFETs when the input voltage is below 5V. Multiplying the gate charge by the on resistance gives a figure of merit, providing a good balance between low load and high load efficiency.
- Slow transition times and oscillations on the voltage and current waveforms dissipate more power during the turn on and turn off of the MOSFETs. A clean layout will minimize parasitic inductance and capaci tance in the gate drive and high current paths. This will allow the fastest transition times and waveforms without oscillations. Low gate charge MOSFETs will transition faster than those with higher gate charge requirements.
- For the same size inductor, a lower value will have fewer turns and therefore, lower winding resistance. However, using too small of a value will require more output capacitors to filter the output ripple, which will force a smaller bandwidth, slower transient response and possible instability under certain conditions.
- Lowering the current sense resistor value will de crease the power dissipated in the resistor. However, it will also increase the overcurrent limit and will require larger MOSFETs and inductor components.
- Use low ESR input capacitors to minimize the power dissipated in the capacitors ESR.

Package Information



16-Pin SOP (M)



16-Pin QSOP (QS)

MICREL INC. 1849 FORTUNE DRIVE SAN JOSE, CA 95131 USA

TEL + 1 (408) 944-0800 FAX + 1 (408) 944-0970 WEB http://www.micrel.com

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